# **CNA1009H** (ON1024)

## Photo Interrupter

For contactless SW and object detection

### Overview

CNA1009H is a transmissive photosensor in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a high sensitivity phototransistor is used as the light detecting element. The two elements are arranged so as to face each other, and objects passing between them are detected.

#### Features

- Highly precise position detection: 0.25 mm
- Gap width: 5 mm
- The type directly attached to PCB (with a positioning pins)

### Absolute Maximum Ratings $T_a = 25^{\circ}C$

F	Symbol	Rating	Unit		
Input (Light emitting diode)	Power dissipation *1	P <sub>D</sub>	75	mW	
	Forward current	I <sub>F</sub>		mA	
	Reverse voltage	V <sub>R</sub>	5	V	
Output (Photo transistor)	Collector-emitter voltage (Base open)	V <sub>CEO</sub> 30		V	
	Emitter-collector voltage (Base open)	V <sub>ECO</sub>	5	V	
	Collector current	I <sub>C</sub>	20	mA	
	Collector power dissipation *2	P <sub>C</sub>	100	mW	
Operating ambient temp	T <sub>opr</sub>	-25 to +85	°C		
Storage temperature	T <sub>stg</sub>	-40 to +100	°C		

Note) \*1: Input power derating ratio is 1.0 mW/°C at  $T_a \ge 25^{\circ}C$ 

\*2: Output power derating ratio is 1.33 mW/°C at  $T_a \ge 25^{\circ}C$ 

### Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Input characteristics	Reverse current	I <sub>R</sub>	$V_R = 3 V$			10	μΑ
	Forward voltage	V <sub>F</sub>	$I_F = 20 \text{ mA}$		1.25	1.4	V
Output characteristics	Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = 10 V$		10	200	nA
Transfer characteristics	Collector current	I <sub>C</sub>	$V_{CC} = 5 \text{ V}, \text{ I}_{\text{F}} = 20 \text{ mA},$ $R_{\text{L}} = 100 \Omega$	0.5		15.0	mA
	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm F} = 40 \text{ mA}, I_{\rm C} = 1 \text{ mA}$			0.4	V
	Rise time *	t <sub>r</sub>	$V_{\rm CC} = 5  \rm V,  I_{\rm C} = 1  \rm mA,$		5.0		μs
	Fall time *	t <sub>f</sub>	$R_L = 100 \Omega$		5.0		μs

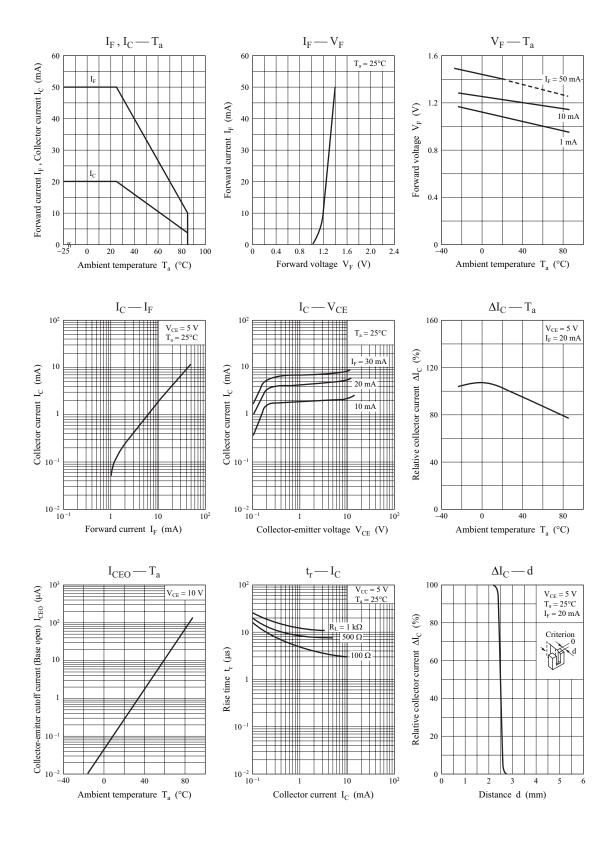
Note) 1. Input and output are practiced by electricity.

2. This device is designed by disregarding radiation. 3. \*: Switching time measurement circuit  $Sig. in \\ 50 \Omega \leqslant R_L$  (Input pulse)  $t_r$ : Rise time  $t_r$ :

Note) The part number in the parenthesis shows conventional part number.

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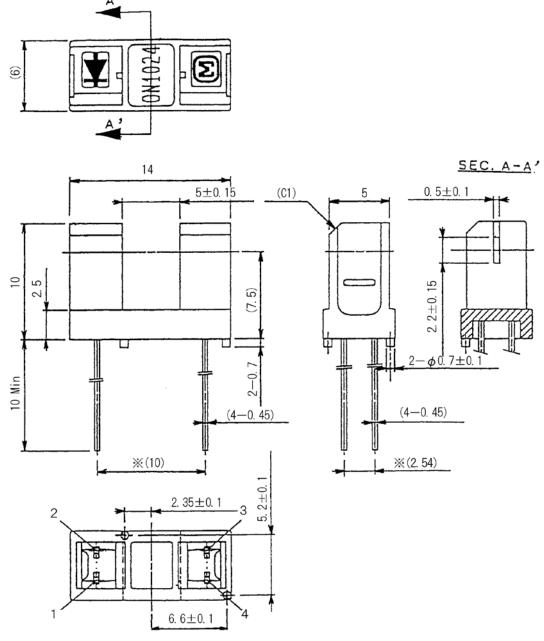
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Package (Unit: mm)

## LSSSIR4S0003



(注 1)(Note1) 指示無き寸法公差は±0.3。/Not appointment tolerance :±0.3.
(注 2)(Note2) ※リード根元寸法とする。/※Indicates root dimensions of lead.
(注 3) 材質グレードを示す。(肉厚 1.5 mm 以上で V-1 規格)

A material grade is indication.

(Note3)

(It is V-1 standard at the equal to or more than 1.5 mm thickness.)

• Pin name

- 1: Anode
- 2: Cathode
- 3: Collector
- 4: Emitter

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